

# SCIENTIFIC REPORTS



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## Corrigendum: Active layers of high-performance lead zirconate titanate at temperatures compatible with silicon nano- and microelectronic devices

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*Scientific Reports* 6:20143; doi: 10.1038/srep20143; published online 03 February 2016; updated on 07 March 2016

The original version of this Article contained an error in the title of the paper, where the word “microelectronic” was incorrectly given as “microelecronic”. This has now been corrected in the PDF and HTML versions of the Article.



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